NSN 5962-01-264-2990

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Body Length:	
0.840 inches	
Body Width:	
0.310 inches	
Body Height:	
0.185 inches	
Maximum Power Dis	sipation Rating:
1.0 watts	
Operating Tempurate	ure Range:
-55.0/+110.0 degrees	celsius
Storage Tempurature	e Range:
-65.0/+150.0 degrees	celsius
Features Provided:	
Hermetically sealed ar	nd burn in and monolithic and dynamic and w/strobe
Inclosure Material:	
Ceramic and glass	
Inclosure Configurat	ion:
Dual-in-line	
Output Logic Form:	
N-type metal oxide-se	miconductor logic
Input Circuit Pattern:	
12 input	
Case Outline Source	And Designator:
D-2 mil-m-38510	
Terminal Surface Tre	atment:
Solder	
Voltage Rating And 1	Type Per Characteristic:
-0.5 volts power source	ce and 7.0 volts power source
Time Rating Per Cha	cteristic:
150.00 nanoseconds	propagation delay time, low to high level output and 150.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type	
Rom	
Test Data Document:	
81349-mil-m-38510 sp	pecification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes com	mercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and per	rformance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And C	Quantity:
16 printed circuit	
Specification Data:	
-	14 government specification
Shelf Life:	

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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